

ROHS

HALOGEN

FREE

Hyperfast Rectifier, 30 A FRED Pt® G5



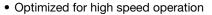
LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V _R	600 V				
V _F at I _F at 125 °C	1.3 V				
t _{rr} (typ.)	22				
I _{FSM}	310				
T _J max.	175 °C				
Package	TO-247AD 2L				
Circuit configuration	Single				

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminal:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 117 °C, D = 0.50	30			
Non-repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, sine wave	310	Α		
Repetitive peak forward current	I _{FRM}	T _C = 117 °C, D = 0.50, f = 20 kHz	60			
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-		
Forward voltage	V	I _F = 30 A	-	1.6	2.1	V	
	V _F	I _F = 30 A, T _J = 125 °C	-	1.3	-		
5		V _R = V _R rated	-	-	20		
Reverse leakage current	IR	$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{ rated}$		-	500	- μΑ	
Junction capacitance	C _T	V _R = 200 V	-	36	_	pF	
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nΗ	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 10$	0 A/μs, V _R = 30 V	-	22	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	39	=.	ns
		T _J = 125 °C		-	50	-	
Dook recovery ourrent	ı	T _J = 25 °C	$I_F = 20 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	14	-	۸
Peak recovery current	I _{RRM}	T _J = 125 °C		-	24	=.	Α
Dovorno rocoveni chargo		T _J = 25 °C		-	253	=.	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	785	-	110
Dovorce recovery time	+	T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _R = 400 V	-	41	-	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	56	-	ns
Dools recovery overent		T _J = 25 °C		-	16	-	^
Peak recovery current	I _{RRM}	T _J = 125 °C		-	27	-	Α
Reverse recovery charge		T _J = 25 °C	""	-	306	-	nC
	Q_{rr}	T _J = 125 °C			952	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.1	°C/W	
Weight			-	5.5	-	g	
			-	0.2	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style: TO-247AD 2L	E5PX3006L				

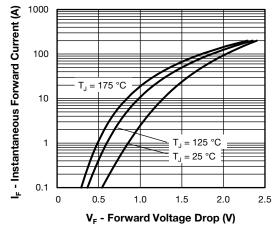


Fig. 1 - Typical Forward Voltage Drop Characteristics

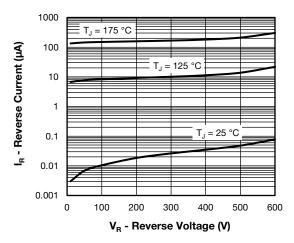


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

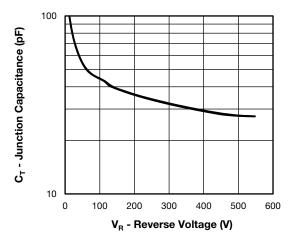


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

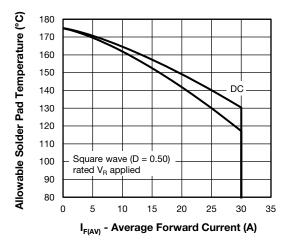


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

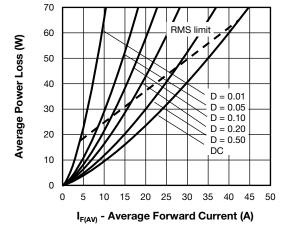


Fig. 5 - Average Power Loss vs. Average Forward Current

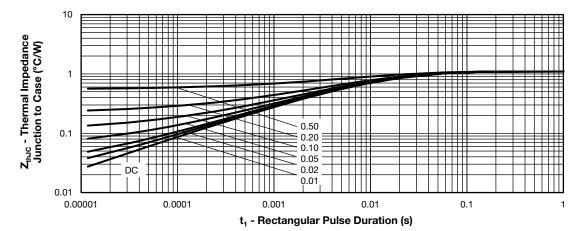


Fig. 6 - Thermal Impedance Z_{thJC} - Characteristics



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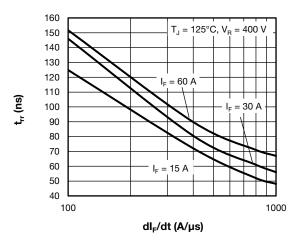


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

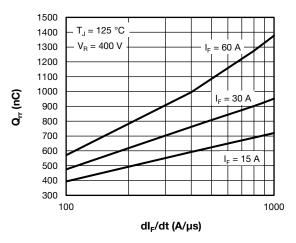


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

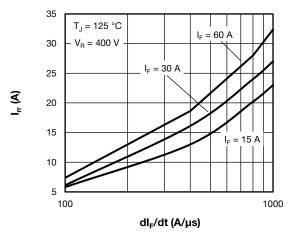


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

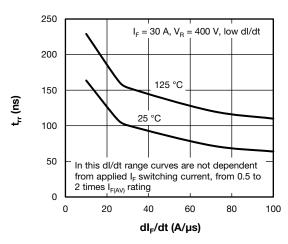


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt

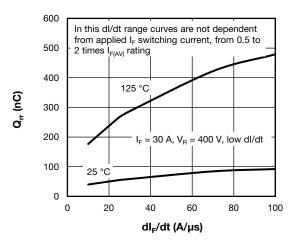


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt

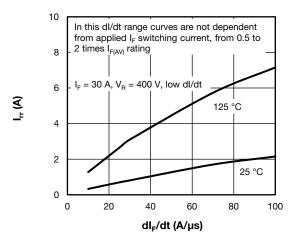


Fig. 12 - Typical Reverse Recovery Current vs. dI_F/dt

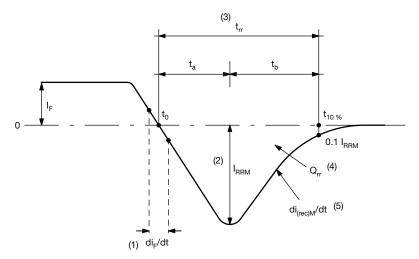


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

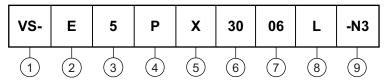
- (1) di_F/dt rate of change of current through zero crossing
- I_{RRM} peak reverse recovery current
- $C_{\rm IRRM}$ poart to receive the state of the state of

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

(5) di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code



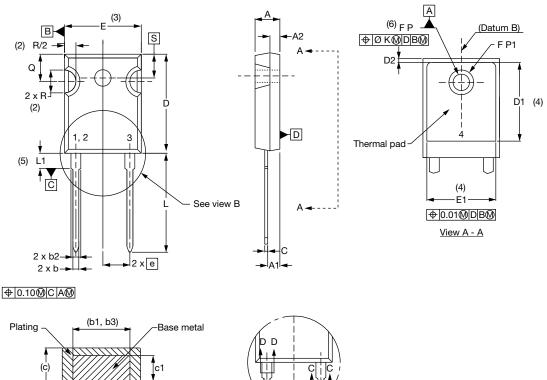
- Vishay Semiconductors product
- Circuit configuration
 - E = single diode
- 5 = Fred generation 5
- Package:
 - P = TO-247 package
- X = hyperfast recovery
- Current rating (30 = 30 A)
- Voltage rating (06 = 600 V)
- Package: L = long lead (TO-247AD)
- Environmental digit:
 - -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-E5PX3006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95536				
Part marking information	www.vishay.com/doc?95648				

TO-247AD 2L

DIMENSIONS in millimeters and inches



D D C C
<u>View B</u>

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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